

*SPECIFICATION AMENDMENTS*

Replace the paragraph beginning at page 1, line 5 with:

The present invention relates to a semiconductor device ~~formed with~~ including transistors, each transistor having a plurality of electrodes.

Replace the paragraph beginning at page 7, line 2 with:

Fig. 5 is a sectional view of the semiconductor device cut along ~~A-A'~~ V-V line in Fig. 3.

Replace the paragraph beginning at page 7, line 4 with:

Fig. 6 is a sectional view of the semiconductor device cut along ~~B-B'~~ VI-VI line in Fig. 3.

Replace the paragraph beginning at page 12, line 10 with:

A semiconductor device according to another embodiment of the present invention will be described below with reference to Figs. 3 to 6. Fig. 3 shows a layout pattern obtained when the semiconductor device of this embodiment is viewed from the top. Fig. 4 shows a layout pattern obtained when the semiconductor device is viewed from the bottom. Fig. 5 is a sectional view of the semiconductor device cut along ~~A-A'~~ V-V line in Fig. 3. Fig. 6 is a sectional view of the semiconductor device cut along ~~B-B'~~ VI-VI line in Fig. 3.